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FailSafe™ PacketClock™ Global Communications Clock Generator

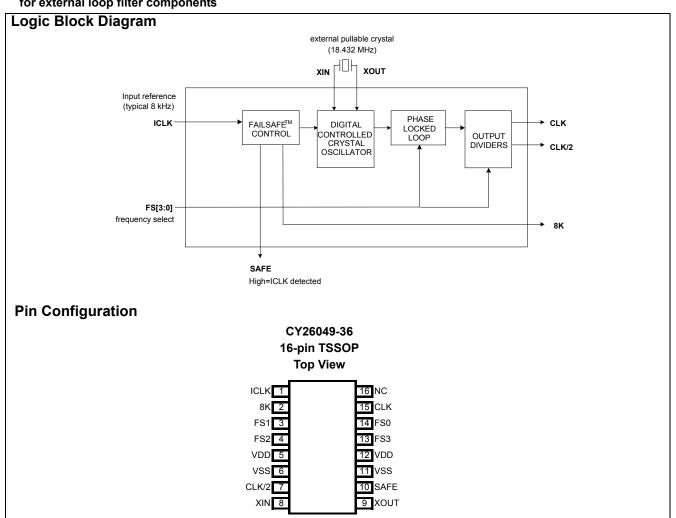
Features

- Fully integrated phase-locked loop (PLL)
- FailSafe[™] output
- PLL driven by a crystal oscillator that is phase aligned with external reference
- Output frequencies selectable and/or programmed to standard communication frequencies
- · Low-jitter, high-accuracy outputs
- Commercial and Industrial operation
- 3.3V ± 5% operation
- 16-lead TSSOP

Benefits

 Integrated high-performance PLL tailored for telecommunications frequency synthesis eliminates the need for external loop filter components

- When reference is in range, SAFE pin is driven high.
- When reference is off, DCXO maintains clock outputs. SAFE pin is low.
- DCXO maintains continuous operation should the input reference clock fail
- Glitch-free transition simplifies system design
- Selectable output clock rates include T1/DS1, E1, T3/DS3, E3, and OC-3.
- Works with commonly available, low-cost 18.432-MHz crystal
- · Zero-ppm error for all output frequencies
- Performance guaranteed for applications that require an extended temperature range
- · Compatible across industry standard design platforms
- Industry standard package with 6.4 x 5.0 mm² footprint and a height profile of just 1.1 mm.





Pin Definitions

Pin Name	Pin Number	Pin Description			
ICLK	1	ference Input Clock; 8 kHz or 10 to 60 MHz.			
8K	2	Clock Output; 8 kHz or high impedance in buffer mode.			
FS1	3	Frequency Select 1; Determines CLK outputs per Table 1.			
FS2	4	Frequency Select 2; Determines CLK outputs per Table 1.			
VDD	5	Voltage Supply; 3.3V.			
VSS	6	Ground			
CLK/2	7	Clock Output; Frequency per Table 1.			
XIN	8	Pullable Crystal Input; 18.432 MHz.			
XOUT	9	Pullable Crystal Output; 18.432 MHz.			
SAFE	10	High = reference ICLK within range, Low = reference ICLK out of range.			
VSS	11	Ground			
VDD	12	Voltage Supply; 3.3V.			
FS3	13	Frequency Select 3; Determines CLK outputs per Table 1.			
FS0	14	Frequency Select 0; Determines CLK outputs per Table 1.			
CLK	15	k Output; Frequency per Table 1.			
NC	16	No Connect			

Selector Guide

Part Number	per Input Frequency Range		Output Frequencies	
	8 kHz or 10 to 60 MHz Reference Input		8 kHz to 155.52 MHz	
	Crystal: 18.432-MHz pullable Crystal per Cypress Specification		Selectable (see <i>Table 1</i>)	

Functional Description

CY26049 is a FailSafe frequency synthesizer with a reference clock input and three clock outputs. The device provides an optimum solution for applications where continuous operation is required in the event of a primary clock failure. The continuous, glitch-free operation is achieved by using a DCXO which serves as a primary clock source. The FailSafe control circuit synchronizes the DCXO with the reference as long as the reference is within the pull range of the crystal.

In the event of a reference clock failure the DCXO maintains the last frequency and phase information of the reference clock. The unique feature of the CY26049-36 is that the DCXO is in fact the primary clocking source. When the reference clock is restored, the DCXO automatically re-synchronizes to the reference. The status of the reference clock input, as detected by the CY26049-36, is reported by the SAFE pin.

In the buffer mode (FS3:FS0 = 1110 or 1111), the CY26049-36 can be used as a jitter attenuator. In this mode, extensive jitter on the input clock will be "filtered", resulting in a low-jitter output clock.



Frequency Select Tables

Table 1. CY26049-36 Frequency Select-Output Decoding Table-External Mode (MHz except as noted)

ICLK	FS3	FS2	FS1	FS0	CLK/2	CLK	8K	Crystal
8 kHz	0	0	0	0	1.544	3.088	8 kHz	18.432
8 kHz	0	0	0	1	2.048	4.096	8 kHz	18.432
8 kHz	0	0	1	0	22.368	44.736	8 kHz	18.432
8 kHz	0	0	1	1	17.184	34.368	8 kHz	18.432
8 kHz	0	1	0	0	77.76	155.52	8 kHz	18.432
8 kHz	0	1	0	1	16.384	32.768	8 kHz	18.432
8 kHz	0	1	1	0	14.352	28.704	8 kHz	18.432
8 kHz	0	1	1	1	High Z ^[1]	High Z ^[1]	High Z ^[1]	18.432
8 kHz	1	0	0	0	18.528	37.056	8 kHz	18.432
8 kHz	1	0	0	1	12.352	24.704	8 kHz	18.432
8 kHz	1	0	1	0	7.68	15.36	8 kHz	18.432
8 kHz	1	0	1	1	High Z ^[1]	High Z ^[1]	High Z ^[1]	18.432
8 kHz	1	1	0	0	12.288	24.576	8 kHz	18.432
8 kHz	1	1	0	1	16.384	32.768	8 kHz	18.432

Table 2. CY26049-36 Frequency Select-Output Decoding Table-Buffer Mode

ICLK	FS3	FS2	FS1	FS0	CLK/2	CLK	8K	Crystal
20 to 60	1	1	1	0	ICLK/2	ICLK	High Z ^[1]	ICLK/2
10 to 30	1	1	1	1	2*ICLK	4*ICLK	High Z ^[1]	ICLK

Note:

^{1.} High Z = high impedance.



Absolute Maximum Conditions

Supply Voltage (V _{DD})	0.5 to +7.0V
DC Input Voltage	–0.5V to V _{DD} +0.5
Storage Temperature (Non-Condensing)	55°C to +125°C
Junction Temperature	–40°C to +125°C

Data Retention @ Tj=125°C	>10 years
Package Power Dissipation	350 mW
ESD (Human Body Model) MIL-STD-883	2000V
(Above which the useful life may be impaired. For lines, not tested.	user guide-

Recommended Pullable Crystal Specifications^[2]

Parameter	Description	Comments	Min.	Тур.	Max.	Units
F _{NOM}	Nominal crystal frequency	Parallel resonance, fundamental mode, AT cut	-	18.432	-	MHz
C _{LNOM}	Nominal load capacitance		_	14	_	pF
R ₁	Equivalent series resistance (ESR)	Fundamental mode	_	_	25	Ω
R ₃ /R ₁	Ratio of third overtone mode ESR to fundamental mode ESR	Ratio used because typical R ₁ values are much less than the maximum spec	3	_	-	
DL	Crystal drive level	No external series resistor assumed	_	0.5	2	mW
F _{3SEPHI}	Third overtone separation from 3*F _{NOM}	High side	400	_	_	ppm
F _{3SEPLO}	Third overtone separation from 3*F _{NOM}	Low side	_	_	-200	ppm
C ₀	Crystal shunt capacitance		_	_	7	pF
C ₀ /C ₁	Ratio of shunt to motional capacitance		180	_	250	
C ₁	Crystal motional capacitance		14.4	18	21.6	fF

Recommended Operating Conditions

Parameter	Description	Min.	Тур.	Max.	Unit
V_{DD}	Operating Voltage	3.15	3.3	3.45	V
T _{AC}	Ambient Temperature (Commercial Temperature)	0	_	70	° C
T _{AI}	Ambient Temperature (Industrial Temperature)	-40	_	85	° C
C _{LOAD}	Max Output Load Capacitance	_	_	15	pF
t _{pu}	Power-up time for all V _{DD} s to reach minimum specified voltage (power ramps must be monotonic)	0.05	_	500	ms
t _{ER(I)}	8 kHz Input Edge Rate, 20% to 80% of V_{DD} = 3.3V	0.07	_	_	V/ns

DC Electrical Specifications (Commercial Temp: 0° to 70°C)

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Unit
I _{OH}	Output High Current	$V_{OH} = V_{DD} - 0.5$, $V_{DD} = 3.3V$ (source)	12	24	_	mA
I _{OL}	Output Low Current	$V_{OL} = 0.5, V_{DD} = 3.3V (sink)$	12	24	_	mA
V _{IH}	Input High Voltage	CMOS Levels	0.7	_	_	V_{DD}
V _{IL}	Input High Voltage	CMOS Levels	-	-	0.3	V_{DD}
I _{IH}	Input High Current	$V_{IH}=V_{DD}$	_	5	10	μΑ
I _{IL}	Input Low Current	V _{IL} =0V	_	5	10	μΑ
C _{IN}	Input Capacitance		_	-	7	pF
l _{oz}	Output Leakage Current	High Z ^[1] output	_	± 5	_	μΑ
I _{DD}	Supply Current	C _{LOAD} = 15 pF, V _{DD} = 3.45V, FS [3:0] = 0100	_	_	45	mA
		C _{LOAD} = 15 pF, V _{DD} = 3.45V, FS [3:0] = 1101	-	-	30	mA

Note:

^{2.} Ecliptek ECX-5761-18.432 M and ECX-5762-18.432 M meets these specifications.



DC Electrical Specifications (Industrial Temp: -40° to 85°C)

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Unit
I _{OH}	Output High Current	$V_{OH} = V_{DD} - 0.5$, $V_{DD} = 3.3V$ (source)	10	20	_	mA
I _{OL}	Output Low Current	$V_{OL} = 0.5, V_{DD} = 3.3V (sink)$	10	20	_	mA
V _{IH}	Input High Voltage	CMOS Levels	0.7	_	_	V_{DD}
V _{IL}	Input High Voltage	CMOS Levels	_	_	0.3	V_{DD}
I _{IH}	Input High Current	$V_{IH} = V_{DD}$	_	5	10	μΑ
I _{IL}	Input Low Current	V _{IL} = 0V	_	5	10	μΑ
C _{IN}	Input Capacitance		_	_	7	pF
l _{OZ}	Output Leakage Current	High Z ^[1] output	_	± 5	_	μΑ
I _{DD}	Supply Current	C _{LOAD} = 15 pF, V _{DD} = 3.45V, FS [3:0] = 0100	_	_	50	mA
		C _{LOAD} = 15 pF, V _{DD} = 3.45V, FS [3:0] = 1101	_	_	35	mA

AC Electrical Specifications (Commercial Temp: 0° to 70° C and Industrial Temp: –40° to 85°C)

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Unit
f _{ICLK-E}	Frequency, Input Clock	Input Clock Frequency, External Mode	1	8.00	_	kHz
f _{ICLK-B}	Frequency, Input Clock	Input Clock Frequency, Buffer Mode	10	_	60	MHz
LR	FailSafe Lock Range ^[3]	Range of reference ICLK for Safe = High	-250	_	+250	ppm
$DC = t_2/t_1$	Output Duty Cycle	Duty Cycle defined in Figure 1, measured at 50% of V_{DD}	45	50	55	%
T _{PJIT1}	Clock Jitter; output > 5 MHz	Period Jitter, Peak to Peak, 10,000 periods	1	_	250	ps
		RMS Period Jitter, RMS	_	_	50	ps
T _{PJIT2}	Clock Jitter; output <5 MHz	Period Jitter, Peak to Peak, 10,000 periods	1	_	500	ps
		RMS Period Jitter, RMS	1	_	100	ps
t ₆	PLL Lock Time	Time for PLL to lock within ± 150 ppm of target frequency	_	_	3	ms
t _{fs_lock}	Failsafe Lock Time	Time for PLL to lock to ICKL (outputs phase aligned with ICKL and Safe = High)	ı	_	7	S
f _{error}	Frequency Synthesis Error	Actual mean frequency error vs. target	-	0	_	ppm
ER	Rising Edge Rate	Output Clock Edge Rate, Measured from 20% to 80% of V_{DD} , C_{LOAD} = 15 pF See <i>Figure 2</i> .	0.8	1.4	2	V/ns
EF	Falling Edge Rate	Output Clock Edge Rate, Measured from 20% to 80% of V_{DD} , C_{LOAD} = 15 pF See <i>Figure 2</i> .	0.8	1.4	2	V/ns

Voltage and Timing Definitions

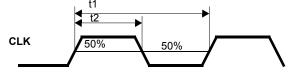


Figure 1. Duty Cycle Definition; DC = t2/t1

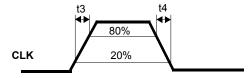


Figure 2. Rise and Fall Time Definitions: ER = $0.6 \times VDD / t3$, EF = $0.6 \times VDD / t4$

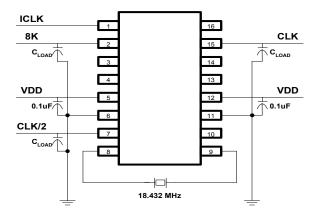
Note

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^{3.} Dependent on crystals chosen and crystal specs.



Test Circuit

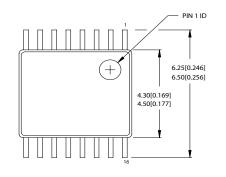


Ordering Information

Ordering Code	Package Type	Operating Temperature Range
CY26049ZC-36	16-lead TSSOP	Commercial 0 to 70°C
CY26049ZC-36T	16-lead TSSOP-Tape and Reel	Commercial 0 to 70°C
CY26049ZI-36	16-lead TSSOP	Industrial –40 to 85°C
CY26049ZI-36T	16-lead TSSOP-Tape and Reel	Industrial –40 to 85°C
Lead Free		·
CY26049ZXC-36	16-lead TSSOP	Commercial 0 to 70°C
CY26049ZXC-36T	16-lead TSSOP-Tape and Reel	Commercial 0 to 70°C
CY26049ZXI-36	16-lead TSSOP	Industrial –40 to 85°C
CY26049ZXI-36T	16-lead TSSOP-Tape and Reel	Industrial –40 to 85°C

Package Diagram

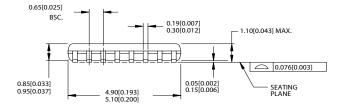
16-lead TSSOP 4.40 MM Body Z16.173

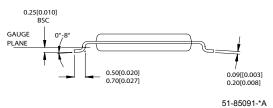


DIMENSIONS IN MM[INCHES] MIN.
MAX.
REFERENCE JEDEC MO-153

PACKAGE WEIGHT 0.05 gms

PART #		
Z16.173	STANDARD PKG.	
ZZ16.173	LEAD FREE PKG.	





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Document History Page

REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	114749	08/08/02	CKN	New Data Sheet
*A	120067	01/06/03	CKN	Changed "FailSafe is a trademark of Silicon Graphics, Inc." to read "FailSafe is a trademark of Cypress Semiconductor"
*B	128000	07/15/03	IJA	Changed Benefits to read "When reference is in range, SAFE pin is driven high Changed first sentence to "CY26049 is a FailSafe frequency synthesizer with a reference clock input and three clock outputs" Changed title from "Failsafe™ PacketClock™ Global Communications Clocks" to "FailSafe™ PacketClock™ Global Communications Clock Generator" Changed definitions in Pin Description Table Replaced format for Absolute Maximum Conditions Replaced Recommended Pullable Crystal Specifications table Added t _{pu} to Recommended Operating Conditions Added I _{IH} and I _{IL} to DC Electrical Specifications Replaced AC Electrical Specifications from Cy26049-16 data sheet Changed Voltage and Timing Definitions to match CY2410 data sheet
*C	244412	See ECN	RGL	Spec. $(t_{ER(1)})$ Input Edge Rate in the Recommended Operating Conditions Table Added Lead Free Devices